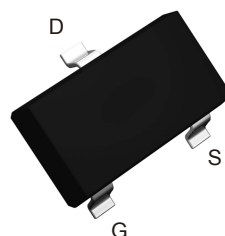
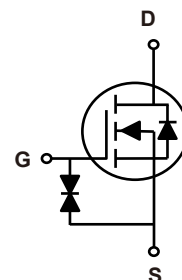


Main Product Characteristics

$V_{(BR)DSS}$	30V
$R_{DS(ON)}$	26m Ω (Max.)
I_D	6.0A



SOT-23



Schematic Diagram

Features and Benefits

- Advanced MOSFET process technology
- Ideal for high efficiency switched mode power supplies
- Low on-resistance with low gate charge
- Fast switching and reverse body recovery



Description

The GSFC3026E utilizes the latest techniques to achieve high cell density and low on-resistance. These features make this device extremely efficient and reliable for use in high efficiency switch mode power supplies and a wide variety of other applications.

Absolute Maximum Ratings ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Max.	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 10	V
Drain Current-Continuous ($T_A=25^{\circ}\text{C}$)	I_D	6.0	A
Drain Current-Continuous ($T_A=100^{\circ}\text{C}$)		3.6	
Drain Current-Pulsed ¹	I_{DM}	28.0	A
Power Dissipation ($T_A=25^{\circ}\text{C}$)	P_D	1.5	W
Power Dissipation-Derate above 25°C		0.012	W/ $^{\circ}\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	100	$^{\circ}\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-55 To +150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 To +150	$^{\circ}\text{C}$

Electrical Characteristics ($T_J=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
On / Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	V
BV _{DSS} Temperature Coefficient	ΔBV _{DSS} /ΔT _J	Reference to 25°C, I _D =1mA	-	0.02	-	V/°C
Drain-Source Leakage Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V, T _J =25°C	-	-	1	μA
		V _{DS} =24V, V _{GS} =0V, T _J =125°C	-	-	10	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±10V, V _{DS} =0V	-	-	±10	μA
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =3A	-	20	26	mΩ
		V _{GS} =2.5V, I _D =2A	-	25	34	
		V _{GS} =1.8V, I _D =1.5A	-	37	50	
Gate Threshold Voltage	V _{GS(th)}	V _{GS} =V _{DS} , I _D =250uA	0.4	0.6	1	V
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)}		-	-2	-	mV/°C
Forward Transconductance	g _{fs}	V _{DS} =5V, I _S =5A	-	14	-	S
Dynamic and Switching Characteristics						
Total Gate Charge ^{2,3}	Q _g	V _{DS} =10V, V _{GS} =4.5V, I _D =5A	-	9.1	-	nC
Gate-Source Charge ^{2,3}	Q _{gs}		-	1.7	-	
Gate-Drain Charge ^{2,3}	Q _{gd}		-	2.2	-	
Turn-On Delay Time ^{2,3}	t _{d(on)}	V _{DD} =10V, V _{GS} =4.5V, R _G =3Ω, I _D =5A	-	11	-	nS
Rise Time ^{2,3}	t _r		-	34	-	
Turn-Off Delay Time ^{2,3}	t _{d(off)}		-	54	-	
Fall Time ^{2,3}	t _f		-	52	-	
Input Capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, F=1MHz	-	650	-	pF
Output Capacitance	C _{oss}		-	145	-	
Reverse Transfer Capacitance	C _{rss}		-	90	-	
Drain-Source Ratings and Characteristics						
Continuous Source Current	I _S	V _G =V _D =0V, Force Current	-	-	6.0	A
Pulsed Source Current	I _{SM}		-	-	28.0	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =3A, T _J =25°C	-	-	1.2	V

Notes:

1. Repetitive rating: Pulsed width limited by maximum junction temperature.
2. Pulse test: Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
3. Essentially independent of operation temperature.

Typical Electrical and Thermal Characteristic Curves

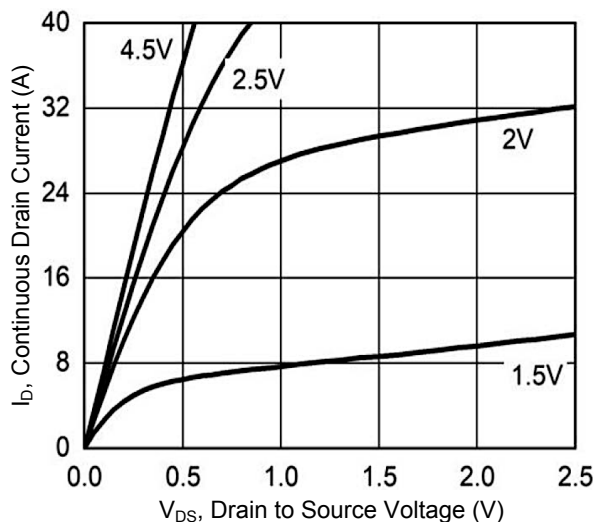


Figure 1. Output Characteristics

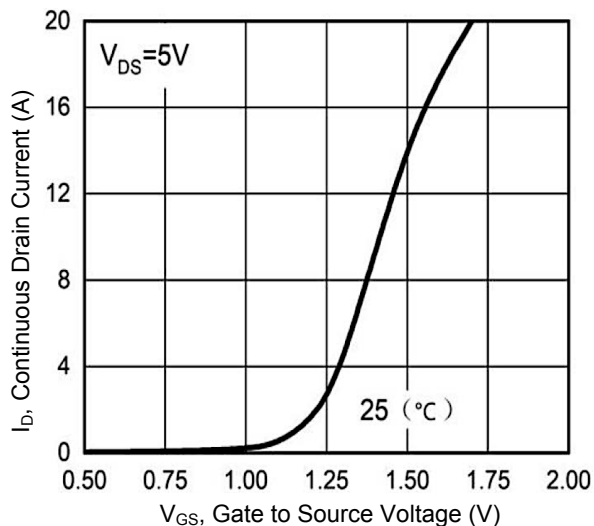


Figure 2. Transfer Characteristics

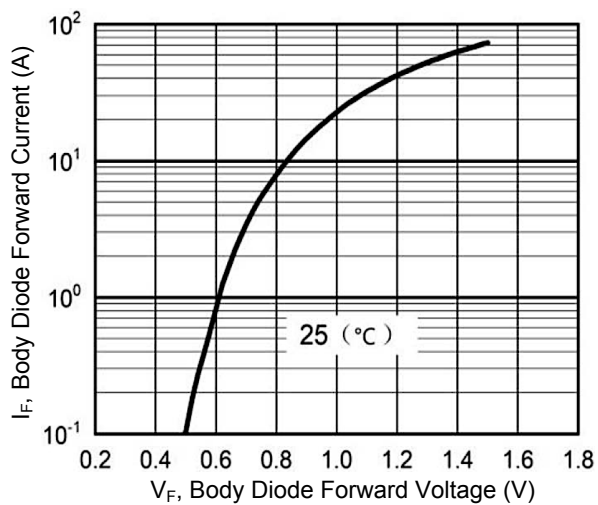


Figure 3. Body Diode Characteristics

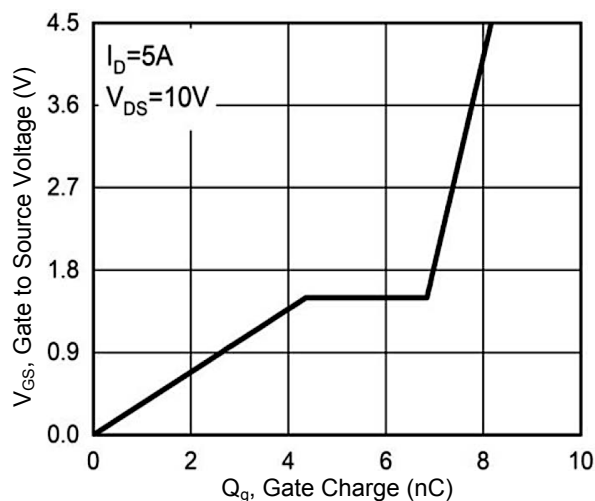


Figure 4. Gate Charge Waveform

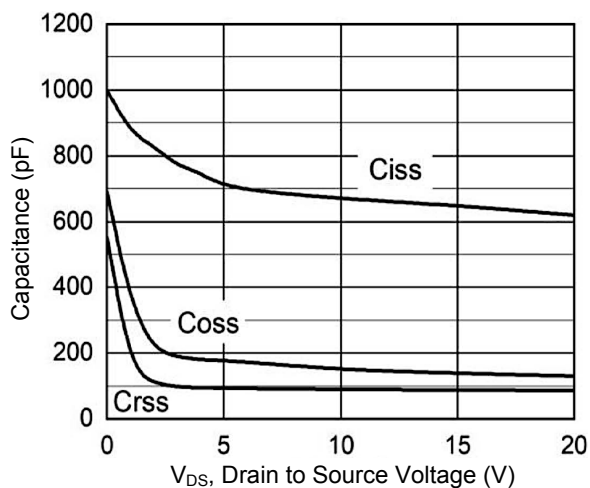


Figure 5. Capacitance Characteristics

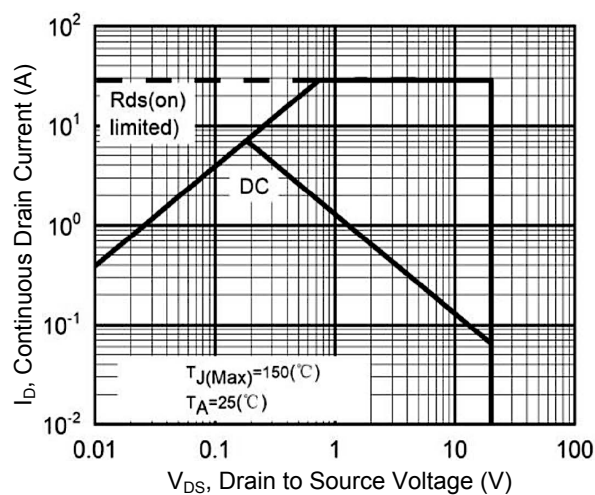
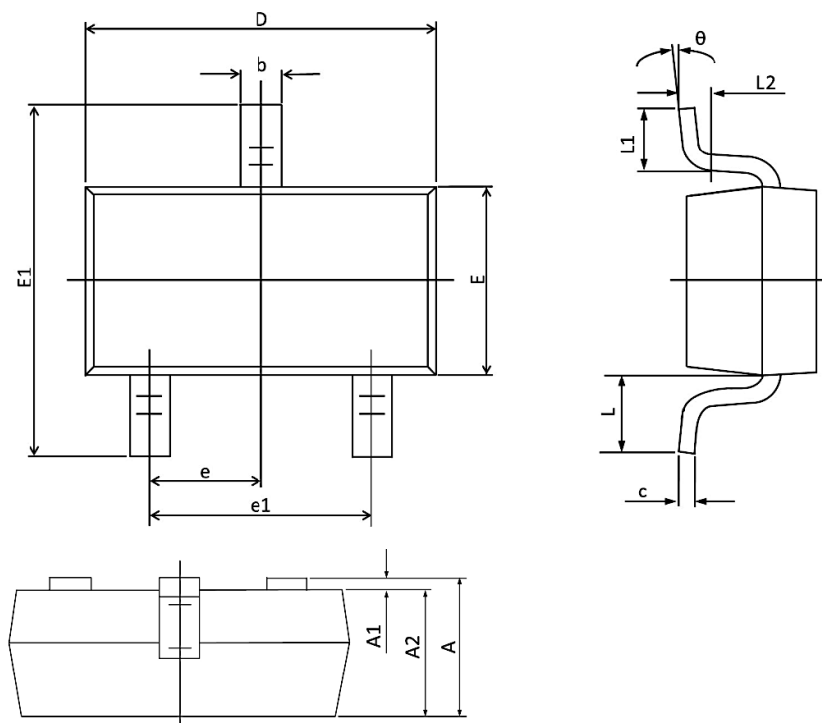


Figure 6. Maximum Safe Operation Area

Package Outline Dimensions (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
L2	0.250 TYP.		0.010 TYP.	
θ	0°	8°	0°	8°

Order Information

Device	Package	Marking	Carrier	Quantity
GSFC3026E	SOT-23	3026E	Tape & Reel	3,000 Pcs / Reel